

General Description

This product family offers state of the art performance. It is designed for high frequency applications where high efficiency and high reliability are required.

Features

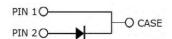
- Low conduction loss due to low VF
- Extremely low switching loss by tiny Qc
- Highly rugged due to better surge current
- Industrial standard quality and reliability

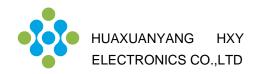
Applications

- UPS
- Power Inverter
- High performance SMPS
- Power factor correction

Ordering Part Number	Package	Marking
HC1D20065G	TO-263	HC1D20065G





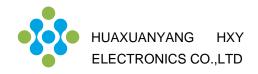


Maximum Ratings (at Tj = 25 °C, unless otherwise specified)

Parameter	Symbol	Value	Unit	
Repetitive Peak Reverse Voltage	V_{RRM}	650	V	
Surge Peak Reverse Voltage	V_{RSM}	650	V	
DC Peak Reverse Voltage	V_R	650	V	
Continuous Forward Current				
T _C = 25°C		51	,	
T _C = 135°C	I _F	26	A	
T _C = 153°C		20		
Repetitive Peak Forward Surge Current				
$T_C = 25^{\circ}C$, $t_p = 10$ ms,Half Sine Pulse	I _{FRM}	102	А	
$T_C = 110^{\circ}C$, $t_p = 10$ ms, H alf Sine Pulse		63		
Non-Repetitive Forward Surge Current				
$T_C = 25^{\circ}C$, $t_p = 10$ ms,Half Sine Pulse	I _{FSM}	150	А	
$T_C = 110^{\circ}C$, $t_p = 10$ ms, H alf Sine Pulse		120		
i ² dt value				
$T_C = 25^{\circ}C$, $t_p = 10$ ms,Half Sine Pulse	∫i ² dt	112	A^2s	
$T_C = 110^{\circ}C$, $t_p = 10$ ms, H alf Sine Pulse		72		
Power dissipation				
T _C = 25°C	P _{tot}	150	W	
T _C = 110°C		65		
Operating junction Range	T _j	-55 to +175	С	
Storage temperature Range	T_{stg}	-55 to +150	С	

Thermal Resistance

Parameter	Symbol	Тур.	Unit
Thermal resistance, junction – case.	R _{thJC}	1.00	°C/W



Electrical Characteristic (at Tc = 25 °C, unless otherwise specified)

Parameter	Symbol	Value			Unit	Test Condition
		min.	typ.	max.	Ullit	rest condition
						I _F =20A
Forward Voltage	V _F	-	1.35	1.5	V	T _j =25°C
		-	1.7	1.8		T _j =175°C
	I _R - 2 40 μA		V _R =650V			
Reverse Current		-	2	40	μΑ	T _j =25°C
		-	10	100		T _j =175°C
					nC	V _R =400V Tj=25°C
Total Capacitive Charge	$Q_{\mathbb{C}}$	ı	52	-		$Q_C = \int_0^{V_R} C(V) dV$
Total Capacitance	С				pF	T _j =25°C,f=1MHz
		-	1018	-		V _R =0V
		-	104	-		V _R =200V
		-	89	-		V _R =400V

Characteristics Curve

Fig 1: Forward Characteristics

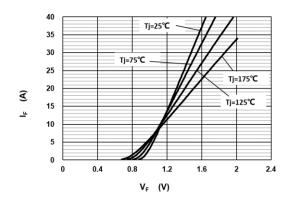


Fig 2: Reverse Characteristics

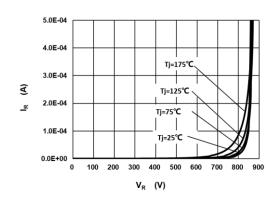


Fig 3: Current Derating

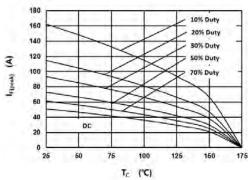


Fig 5: Capacitance vs. Reverse Voltage

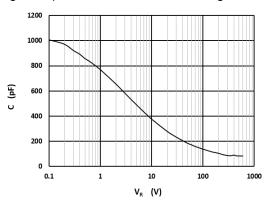


Fig 7: Typical Capacitance Stored Energy

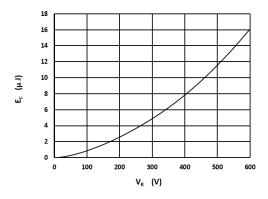


Fig 4: Power Derating

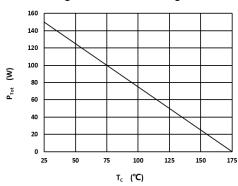


Fig 6: Reverse Charge vs. Reverse Voltage

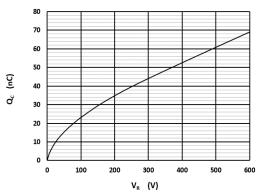
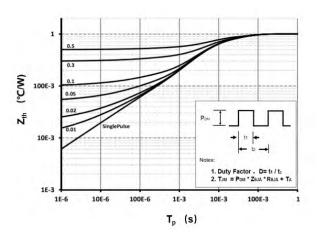
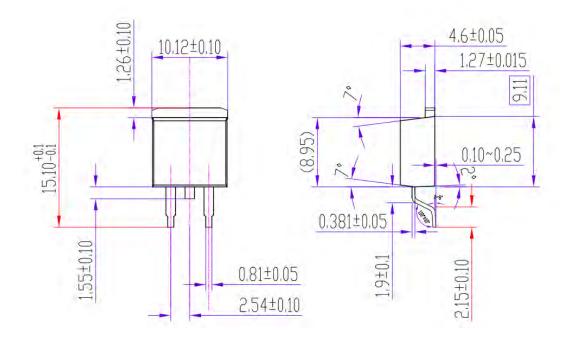


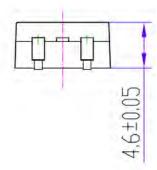
Fig 8: Transient Thermal Impandance

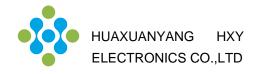


Package Dimensions

Package TO-263







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